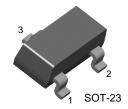


## BCX70H

## **General Purpose Transistor**



# **NPN Epitaxial Silicon Transistor**

### 1. Base 2. Emitter 3. Collector

## **Absolute Maximum Ratings** $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	45	V
V <sub>CEO</sub>	Collector-Emitter Voltage	45	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
I <sub>C</sub>	Collector Current	200	mA
P <sub>C</sub>	Collector Power Dissipation	350	mW
T <sub>STG</sub>	Storage Temperature	-55 ~ 150	°C

Refer to KST3904 for graphs

# $\textbf{Electrical Characteristics} \ \, \textbf{T}_{a} \text{=-} 25 ^{\circ} \textbf{C} \ \, \text{unless otherwise noted}$

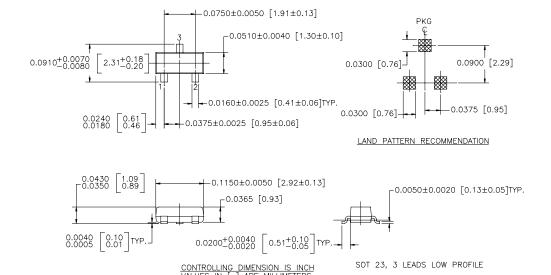
Symbol	Parameter	Test Condition	Min.	Max.	Units
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> =2.0mA, I <sub>B</sub> =0	45		V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> =1.0μA, I <sub>C</sub> =0	5		V
I <sub>CES</sub>	Collector Cut-off Current	$V_{CE}=32V, V_{BE}=0$		20	nA
I <sub>EBO</sub>	Emitter Cut-off Current	V <sub>EB</sub> =4V, I <sub>C</sub> =0		20	nA
h <sub>FE</sub>	DC Current Gain	$V_{CE}$ =5V, $I_{C}$ =10 $\mu$ A $V_{CE}$ =5V, $I_{C}$ =2.0 $\mu$ A $V_{CE}$ =1V, $I_{C}$ =50 $\mu$ A	20 180 70	310	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> =10mA, I <sub>B</sub> =0.25mA I <sub>C</sub> =50mA, I <sub>B</sub> =1.25mA		0.35 0.55	V V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> =10mA, I <sub>B</sub> =0.25mA I <sub>C</sub> =50mA, I <sub>B</sub> =1.25mA	0.6 0.7	0.85 1.05	V V
V <sub>BE</sub> (on)	Base-Emitter On Voltage	V <sub>CE</sub> =5V, I <sub>C</sub> =2.0mA	0.55	0.75	V
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> =5V, I <sub>C</sub> =10mA, f=100MHz	125		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CE</sub> =10V, I <sub>E</sub> =0, f=1MHz		4.5	pF
NF	Noise Figure	$V_{CE}$ =5V, $I_{C}$ =0.2mA $R_{S}$ =2K $\Omega$ , f=1KHz		6	dB
t <sub>ON</sub>	Turn On Time	I <sub>C</sub> =10mA, I <sub>B1</sub> =1.0mA		150	ns
t <sub>OFF</sub>	Turn Off Time	$V_{BB}$ =3.6V, $I_{B2}$ =1.0mA $R_1$ = $R_2$ =5K $\Omega$ , $R_L$ =990 $\Omega$		800	ns

Marking



# **Package Dimensions**

## **SOT-23**



NOTE: UNLESS OTHERWISE SPECIFIED

- 1. STANDARD LEAD FINISH 150 MICROINCHES / 3.81 MICROMETERS MINIMUM TIN / LEAD (SOLDER) ON ALLOY 42
- 2. REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE G, DATED JUL 1993

Dimensions in Millimeters

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Bottomless™	FAST <sup>®</sup>	LittleFET™	Power247™	SuperSOT™-3
CoolFET™	FASTr™	MicroFET™	PowerTrench <sup>®</sup>	SuperSOT™-6
CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
DOME™	GlobalOptoisolator™	MICROWIRE™	$QS^{TM}$	SyncFET™
EcoSPARK™	GTO™	MSX™	QT Optoelectronics™	TinyLogic™
E <sup>2</sup> CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	$I^2C^{TM}$	$OCX^{TM}$	RapidConfigure™	UHC™
Across the board.	. Around the world.™	OCXPro™	RapidConnect™	UltraFET <sup>®</sup>
The Power Franchise™		OPTOLOGIC <sup>®</sup>	SILENT SWITCHER®	$VCX^{TM}$
Programmable Active Droop™		OPTOPLANAR™	SMART START™	

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